NUP6101DMR2

Unidirectional TVS Array for High-Speed Data Line Protection

The NUP6101DMR2 transient voltage suppressor is designed to protect equipment attached to up to six high speed communication lines from ESD, EFT, and lightning.

Features:

- Micro8 Package
- Peak Power 300 Watts 8 x 20 μS
- ESD Rating:

IEC 61000-4-2 (ESD) 15 kV (air) 8 kV (contact)

IEC 61000-4-4 (EFT) 40 A (5/5 ns)

IEC 61000–4–5 (lightning) 23 A (8/20 μs)

• UL Flammability Rating of 94 V-0

Typical Applications:

- High Speed Communication Line Protection
- 5.0 V Data and I/O Lines
- Microprocessor Based Equipment
- LAN/WAN Equipment
- Servers
- Notebook and Desktop PC
- Instrumentation

MAXIMUM RATINGS

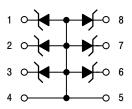
Rating	Symbol	Value	Unit
Peak Power Dissipation 8 x 20 μs @ T _A = 25°C (Note 1)	P _{pk}	300	W
Peak Pulse Current 8 x 20 μs @ T _A = 25°C (Note 1)	Ірр	17	Α
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum 10 Seconds Duration	TL	260	°C

1. Non-repetitive current pulse 8 x 20 μ S exponential decay waveform

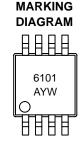


ON Semiconductor™

http://onsemi.com

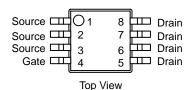






6101 = Device Code A = Assembly Location Y = Year W = Work Week

PIN ASSIGNMENT



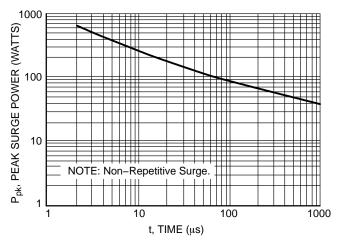
ORDERING INFORMATION

Device	Package	Shipping [†]
NUP6101DMR2	Micro8	4000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Stand-off Voltage	V_{BRWM}	_	_	5.0	V
Reverse Breakdown Voltage @ I _t = 1.0 mA	V_{BR}	6.0	-	-	V
Reverse Leakage Current @ V _{RWM} = 5.0 Volts, T = 25°C	I _R	-	-	20	μΑ
Maximum Clamping Voltage @ I _{PP} = 1.0 A, 8 x 20 μS	V _C	-	-	9.8	V
Maximum Clamping Voltage @ I _{PP} = 5.0 A, 8 x 20 μS	V _C		-	11	V
Maximum Peak Pulse Current	I _{PP}	-	-	17	Α
Junction Capacitance Between I/O Pins and Ground @ $V_R = 0 V$, 1.0 MHz	CJ	_	_	400	pF



100 PEAK VALUE I_{RSM} @ 8 μs 90 PULSE WIDTH (t_P) IS DEFINED AS THAT POINT WHERE THE % OF PEAK PULSE CURRENT 80 70 PEAK CURRENT DECAY = $8 \mu s$ 60 · HALF VALUE I_{RSM}/2 @ 20 μs 50 40 30 20 10 0 0 t, TIME (μs)

Figure 1. Pulse Width

Figure 2. $8 \times 20~\mu s$ Pulse Waveform

NUP6101DMR2

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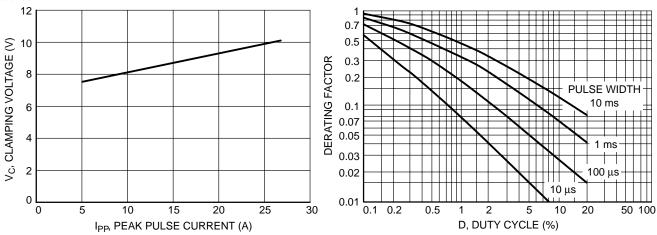


Figure 3. Clamping Voltage versus Peak Pulse Current

Figure 4. Typical Derating Factor for Duty Cycle

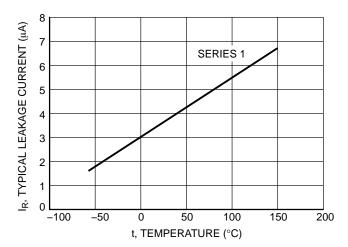
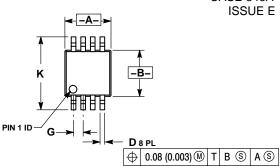
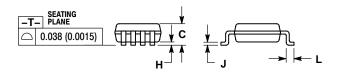


Figure 5. Typical Leakage Current versus Temperature

PACKAGE DIMENSIONS

Micro8 CASE 846A-02





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
c		1.10		0.043
D	0.25	0.40	0.010	0.016
G	0.65	BSC	0.026 BSC	
H	0.05	0.15	0.002	0.006
7	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

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